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September 1983 Revised May 2005

# MM74HC245A Octal 3-STATE Transceiver

#### **General Description**

The MM74HC245A 3-STATE bidirectional buffer utilizes advanced silicon-gate CMOS technology, and is intended for two-way asynchronous communication between data buses. It has high drive current outputs which enable high speed operation even when driving large bus capacitances. This circuit possesses the low power consumption and high noise immunity usually associated with CMOS circuitry, yet has speeds comparable to low power Schottky TTL circuits.

This device has an active LOW enable input  $\overline{G}$  and a direction control input, DIR. When DIR is HIGH, data flows from the A inputs to the B outputs. When DIR is LOW, data flows from the B inputs to the A outputs. The MM74HC245A transfers true data from one bus to the other.

This device can drive up to 15 LS-TTL Loads, and does not have Schmitt trigger inputs. All inputs are protected from damage due to static discharge by diodes to  $V_{CC}$  and ground.

#### **Features**

- Typical propagation delay: 13 ns
- Wide power supply range: 2-6V
- Low quiescent current: 80 µA maximum (74 HC)
- 3-STATE outputs for connection to bus oriented systems
- High output drive: 6 mA (minimum)
- Same as the 645

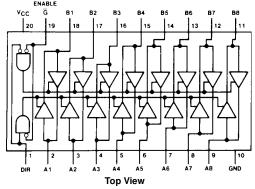
#### **Ordering Code:**

Order Number	Package Number	Package Description
MM74HC245AWM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HC245ASJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC245AMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC245AN	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

#### **Connection Diagram**

#### Pin Assignments for DIP, SOIC, SOP and TSSOP



#### **Truth Table**

Control Inputs		Operation
G	DIR	
L	L	B data to A bus
L	Н	A data to B bus
Н	X	Isolation

- H = HIGH Level
- L = LOW Level X = Irrelevant

#### Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V <sub>CC</sub> )	-0.5 to $+7.0$ V
DC Input Voltage DIR and $\overline{\mathbf{G}}$ pins (V <sub>IN</sub> )	$-1.5$ to $V_{CC}$ +1.5V
DC Input/Output Voltage (V <sub>IN</sub> , V <sub>OUT</sub> )	$-0.5$ to $V_{CC}$ +0.5V
Clamp Diode Current (I <sub>CD</sub> )	±20 mA
DC Output Current, per pin (I <sub>OUT</sub> )	±35 mA
DC $V_{CC}$ or GND Current, per pin ( $I_{CC}$ )	±70 mA
Storage Temperature Range (T <sub>STG</sub> )	-65°C to +150°C
Power Dissipation (P <sub>D</sub> )	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T <sub>L</sub> )	
(Soldering 10 seconds)	260°C

# **Recommended Operating Conditions**

	Min	Max	Units
Supply Voltage (V <sub>CC</sub> )	2	6	V
DC Input or Output Voltage			
$(V_{IN}, V_{OUT})$	0	$V_{CC}$	٧
Operating Temperature Range (T <sub>A</sub> )	-40	+85	°C
Input Rise/Fall Times			
$(t_r, t_f)$ $V_{CC} = 2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns

Note 1: Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

#### DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V <sub>CC</sub>	T <sub>A</sub> = 25°C		$T_A = -40 \text{ to } 85^{\circ}\text{C}$	T <sub>A</sub> = -55 to 125°C	Units	
Symbol	raiailletei		*CC	Тур		Guaranteed L	imits	Units	
V <sub>IH</sub>	Minimum HIGH Level Input		2.0V		1.5	1.5	1.5	٧	
	Voltage		4.5V		3.15	3.15	3.15	V	
			6.0V		4.2	4.2	4.2	V	
V <sub>IL</sub>	Maximum LOW Level Input		2.0V		0.5	0.5	0.5	V	
	Voltage		4.5V		1.35	1.35	1.35	V	
			6.0V		1.8	1.8	1.8	V	
V <sub>OH</sub>	Minimum HIGH Level Output	$V_{IN} = V_{IH}$ or $V_{IL}$							
	Voltage	$ I_{OUT}  \le 20 \ \mu A$	2.0V	2.0	1.9	1.9	1.9	V	
			4.5V	4.5	4.4	4.4	4.4	V	
			6.0V	6.0	5.9	5.9	5.9	V	
		$V_{IN} = V_{IH}$ or $V_{IL}$							
		$ I_{OUT}  \le 6.0 \text{ mA}$	4.5V	4.2	3.98	3.84	3.7	V	
		$ I_{OUT}  \le 7.8 \text{ mA}$	6.0V	5.7	5.48	5.34	5.2	V	
V <sub>OL</sub>	Maximum LOW Level Output	$V_{IN} = V_{IH}$ or $V_{IL}$							
	Voltage	$ I_{OUT}  \leq 20 \; \mu A$	2.0V	0	0.1	0.1	0.1	V	
			4.5V	0	0.1	0.1	0.1	V	
			6.0V	0	0.1	0.1	0.1	V	
		$V_{IN} = V_{IH}$ or $V_{IL}$							
		$ I_{OUT}  \le 6.0 \text{ mA}$	4.5V	0.2	0.26	0.33	0.4	V	
		$ I_{OUT}  \le 7.8 \text{ mA}$	6.0V	0.2	0.26	0.33	0.4	V	
I <sub>IN</sub>	Input Leakage	V <sub>IN</sub> = V <sub>CC</sub> to GND	6.0V		±0.1	±1.0	±1.0	μΑ	
	Current (G and DIR)								
loz	Maximum 3-STATE Output	V <sub>OUT</sub> = V <sub>CC</sub> or GND	6.0V		±0.5	±5.0	±10	μА	
	Leakage Current	Enable $\overline{G} = V_{IH}$							
Icc	Maximum Quiescent Supply	V <sub>IN</sub> = V <sub>CC</sub> or GND	6.0V		8.0	80	160	μА	
	Current	$I_{OUT} = 0 \mu A$							

Note 4: For a power supply of 5V  $\pm$ 10% the worst case output voltages ( $V_{OH}$ , and  $V_{OL}$ ) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case  $V_{IH}$  and  $V_{IL}$  occur at  $V_{CC} = 5.5V$  and 4.5V respectively. (The  $V_{IH}$  value at 5.5V is 3.85V.) The worst case leakage current ( $I_{IN}$ ,  $I_{CC}$ , and  $I_{OZ}$ ) occur for CMOS at the higher voltage and so the 6.0V values should be used.

#### **AC Electrical Characteristics**

 $V_{CC} = 5V, T_A = 25^{\circ}C, t_r = t_f = 6ns$ 

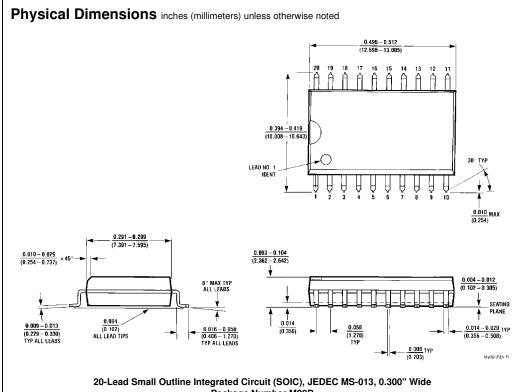
Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation Delay	C <sub>L</sub> = 45 pF	12	17	ns
t <sub>PZH</sub> , t <sub>PZL</sub>	Maximum Output Enable	$R_L = 1 k\Omega$	24	35	ns
	Time	$C_L = 45 \text{ pF}$			
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Maximum Output Disable	$R_L = 1 k\Omega$	18	25	ns
	Time	$C_L = 5 pF$			

#### **AC Electrical Characteristics**

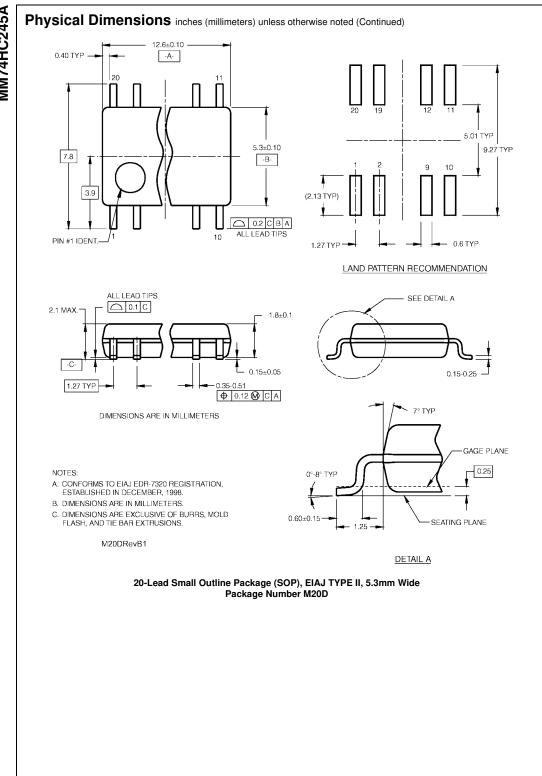
 $\mbox{V}_{\mbox{CC}} = 2.0\mbox{V}$  to 6.0V,  $\mbox{C}_{\mbox{L}} = 50$  pF,  $t_r = t_f = \mbox{6ns}$  (unless otherwise specified)

Symbol	Parameter	Conditions	V <sub>CC</sub>	T <sub>A</sub> = 25°C		T <sub>A</sub> = -40 to 85°C	T <sub>A</sub> = -55 to 125°C	Units
Symbol	Farameter	Conditions	• 66	Тур		Guaranteed L		
t <sub>PHL</sub> ,	Maximum Propagation	C <sub>L</sub> = 50 pF	2.0V	31	90	113	135	ns
t <sub>PLH</sub>	Delay	$C_L = 150 pF$	2.0V	41	96	116	128	ns
		C <sub>L</sub> = 50 pF	4.5V	13	18	23	27	ns
		$C_L = 150 \text{ pF}$	4.5V	17	22	28	33	ns
		C <sub>L</sub> = 50 pF	6.0V	11	15	19	23	ns
		$C_L = 150 \text{ pF}$	6.0V	14	19	23	28	ns
t <sub>PZH</sub> ,	Maximum Output Enable	$R_L = 1 k\Omega$						
t <sub>PZL</sub>	Time	C <sub>L</sub> = 50 pF	2.0V	71	190	240	285	ns
		$C_L = 150 pF$	2.0V	81	240	300	360	ns
		C <sub>L</sub> = 50 pF	4.5V	26	38	48	57	ns
		C <sub>L</sub> = 150 pF	4.5V	31	48	60	72	ns
		C <sub>L</sub> = 50 pF	6.0V	21	32	41	48	ns
		$C_L = 150 pF$	6.0V	25	41	51	61	ns
t <sub>PHZ</sub> ,	Maximum Output Disable	$R_L = 1 k\Omega$	2.0V	39	135	169	203	ns
t <sub>PLZ</sub>	Time	$C_L = 50 pF$	4.5V	20	27	34	41	ns
			6.0V	18	23	29	34	ns
$t_{TLH}$ , $t_{THL}$	Output Rise and Fall Time	C <sub>L</sub> =50 pF	2.0V	20	60	75	90	ns
			4.5V	6	12	15	18	ns
			6.0V	5	10	13	15	ns
C <sub>PD</sub>	Power Dissipation	$\overline{G} = V_{IL}$		50				pF
	Capacitance (Note 5)	$\overline{G} = V_{IH}$		5				pF
C <sub>IN</sub>	Maximum Input Capacitance			5	10	10	10	pF
C <sub>IN/OUT</sub>	Maximum Input/Output			15	20	20	20	pF
	Capacitance, A or B							

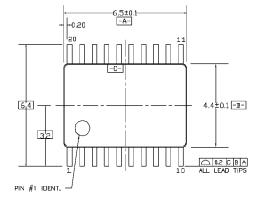
 $\textbf{Note 5: } C_{PD} \text{ determines the no load dynamic power consumption, } P_D - C_{PD} V_{CC}^2 f \cdot I_{CC} V_{CC}, \text{ and the no load dynamic current consumption, } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and the no load dynamic current consumption, } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and the no load dynamic current consumption, } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and the no load dynamic current consumption, } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and the no load dynamic current consumption, } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and the no load dynamic current consumption, } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and the no load dynamic current consumption, } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and the no load dynamic current consumption, } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and the no load dynamic current consumption, } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and the no load dynamic current consumption, } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_{CC} V_{CC}, \text{ and } I_S - C_{PD} V_{CC} f \cdot I_S - C_{PD} V_{CC} f$ 

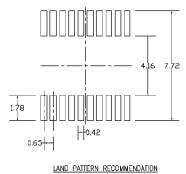


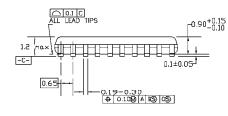
20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Package Number M20B



#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





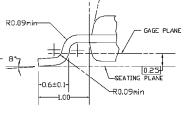


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- A. CONFORMS TO JEDEC REGISTRATION MD-153, VARIATION AC, REF NOTE 6, DATE 7/93.
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- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

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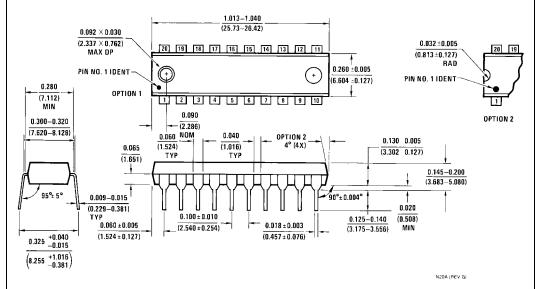


DETAIL A

#### MTC20REVD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC20

#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N20A

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